

SKKT 106, SKKT 106B, SKKH 106



SEMIPACK® 1

Thyristor / Diode Modules

SKKT 106

SKKT106B

SKKH 106

Features

- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- UL recognized, file no. E 63 532

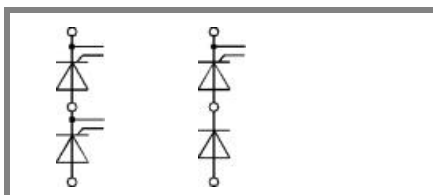
Typical Applications

- DC motor control (e. g. for machine tools)
- AC motor soft starters
- Temperature control (e. g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

1) See the assembly instructions

| V_{RSM} V | V_{RRM}, V_{DRM} V | $I_{TRMS} = 180$ A (maximum value for continuous operation) $I_{TAV} = 106$ A (sin. 180; $T_c = 85$ °C) | | |
|----------------|-------------------------|--|--------------|--------------|
| 900 | 800 | SKKT 106/08E | SKKT 106B08E | SKKH 106/08E |
| 1300 | 1200 | SKKT 106/12E | SKKT 106B12E | SKKH 106/12E |
| 1500 | 1400 | SKKT 106/14E | SKKT 106B14E | SKKH 106/14E |
| 1700 | 1600 | SKKT 106/16E | SKKT 106B16E | SKKH 106/16E |
| 1900 | 1800 | SKKT 106/18E | SKKT 106B18E | SKKH 106/18E |

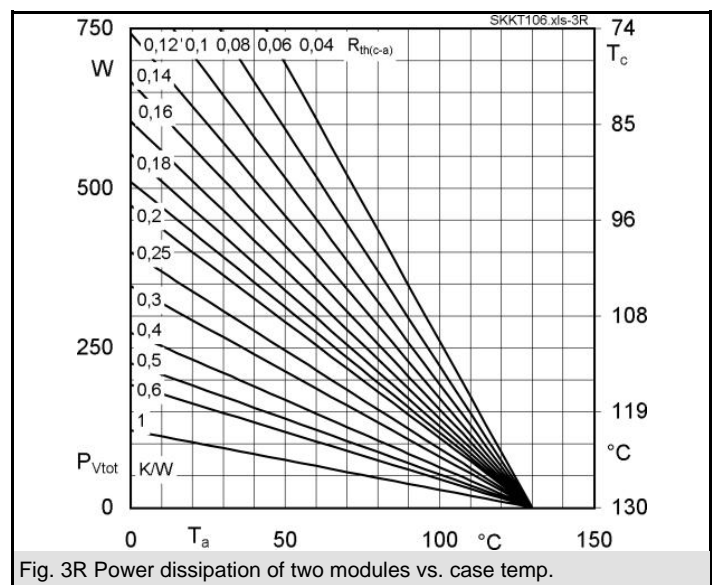
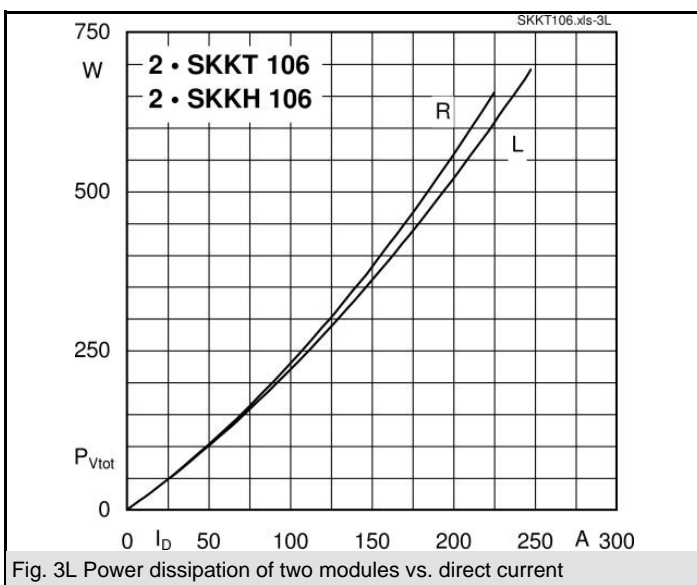
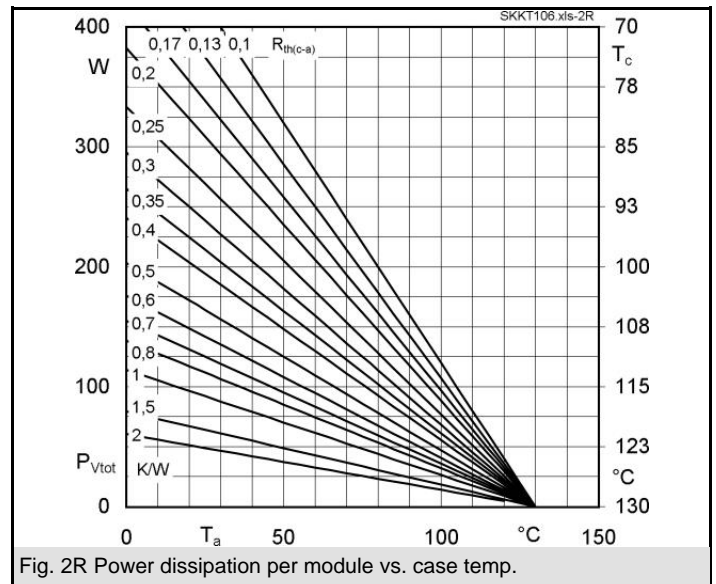
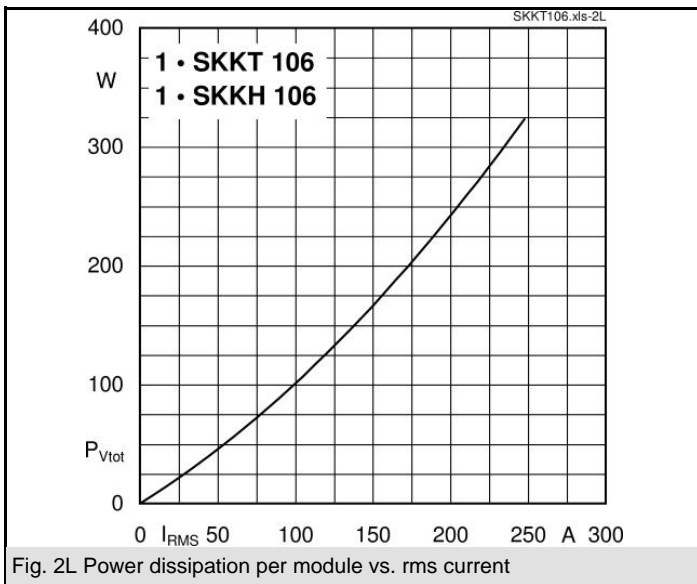
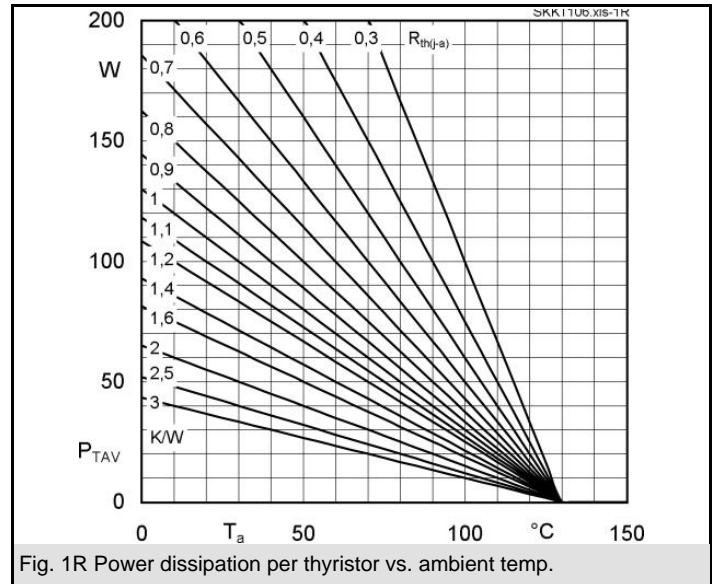
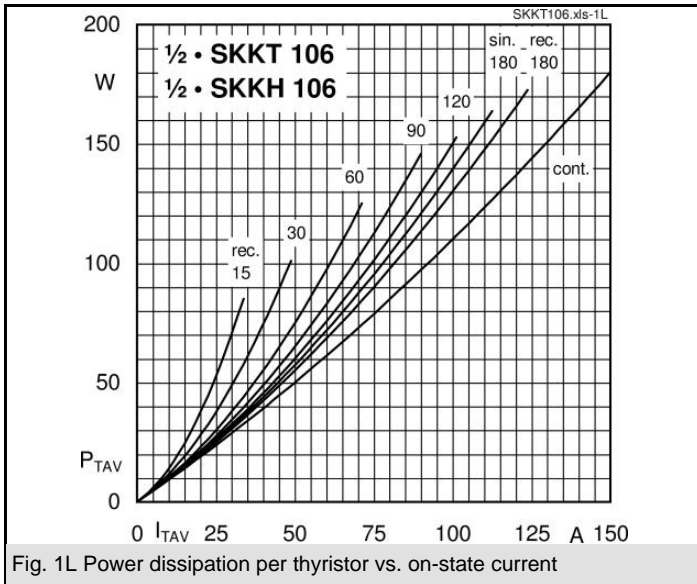
| Symbol | Conditions | Values | Units |
|------------------|---|------------------------|-------|
| I_{TAV} | sin. 180; $T_c = 85$ (100) °C | 106 (78) | A |
| I_D | P3/180F; $T_a = 35$ °C; B2 / B6 P16/200F; $T_a = 35$ °C; B2 / B6 | 145 / 180 190 / 260 | A |
| I_{RMS} | P3/180F; $T_a = 35$ °C; W1 / W3 | 200 / 3 * 140 | A |
| I_{TSM} | $T_{vj} = 25$ °C; 10 ms $T_{vj} = 130$ °C; 10 ms | 2250 1900 | A |
| i^2t | $T_{vj} = 25$ °C; 8,3 ... 10 ms $T_{vj} = 130$ °C; 8,3 ... 10 ms | 25000 18000 | A²s |
| V_T | $T_{vj} = 25$ °C; $I_T = 300$ A | max. 1,65 | V |
| $V_{T(TO)}$ | $T_{vj} = 130$ °C | 0,9 | V |
| r_T | $T_{vj} = 130$ °C | 2 | mΩ |
| $I_{DD}; I_{RD}$ | $T_{vj} = 130$ °C; $V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$ | max. 20 | mA |
| t_{gd} | $T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/μs | 1 | μs |
| t_{gr} | $V_D = 0,67 * V_{DRM}$ | 2 | μs |
| $(di/dt)_{cr}$ | $T_{vj} = 130$ °C | max. 150 | A/μs |
| $(dv/dt)_{cr}$ | $T_{vj} = 130$ °C | max. 1000 | V/μs |
| t_q | $T_{vj} = 130$ °C | 100 | μs |
| I_H | $T_{vj} = 25$ °C; typ. / max. | 150 / 250 | mA |
| I_L | $T_{vj} = 25$ °C; $R_G = 33$ Ω; typ. / max. | 300 / 600 | mA |
| V_{GT} | $T_{vj} = 25$ °C; d.c. | min. 3 | V |
| I_{GT} | $T_{vj} = 25$ °C; d.c. | min. 150 | mA |
| V_{GD} | $T_{vj} = 130$ °C; d.c. | max. 0,25 | V |
| I_{GD} | $T_{vj} = 130$ °C; d.c. | max. 6 | mA |
| $R_{th(j-c)}$ | cont.; per thyristor / per module | 0,28 / 0,14 | K/W |
| $R_{th(j-c)}$ | sin. 180; per thyristor / per module | 0,3 / 0,15 | K/W |
| $R_{th(j-c)}$ | rec. 120; per thyristor / per module | 0,32 / 0,16 | K/W |
| $R_{th(c-s)}$ | per thyristor / per module | 0,2 / 0,1 | K/W |
| T_{vj} | | - 40 ... + 130 | °C |
| T_{stg} | | - 40 ... + 125 | °C |
| V_{isol} | a. c. 50 Hz; r.m.s.; 1 s / 1 min. | 3600 / 3000 | V~ |
| M_s | to heatsink | 5 ± 15 % ¹⁾ | Nm |
| M_t | to terminal | 3 ± 15 % | Nm |
| a | | 5 * 9,81 | m/s² |
| m | approx. | 95 | g |
| Case | SKKT | A 46 | |
| | SKKT ...B | A 48 | |
| | SKKH | A 47 | |



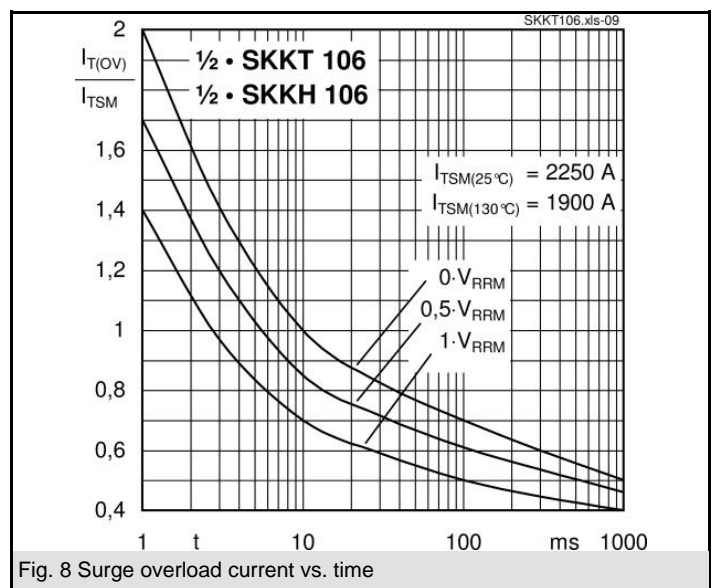
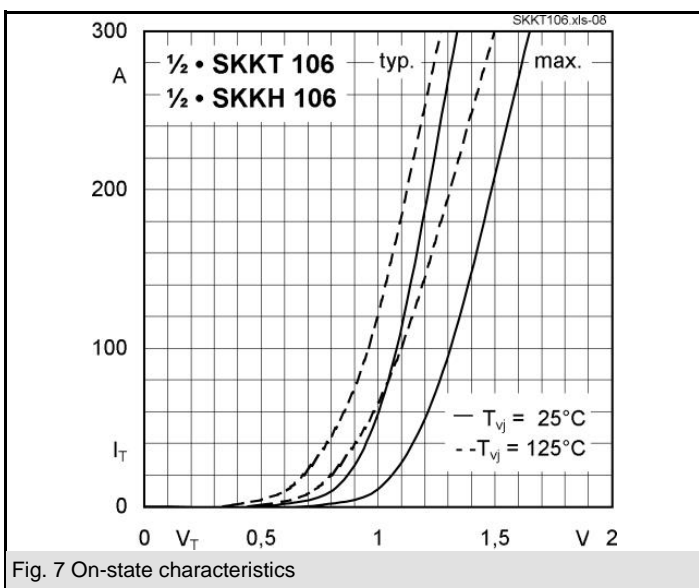
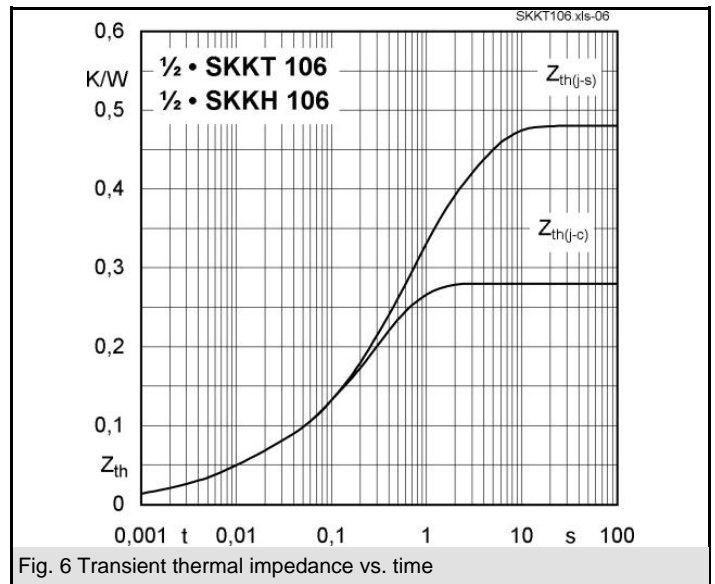
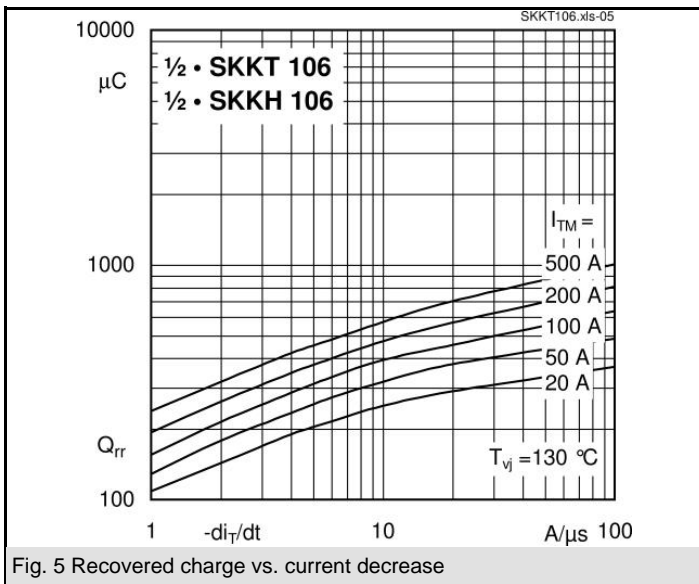
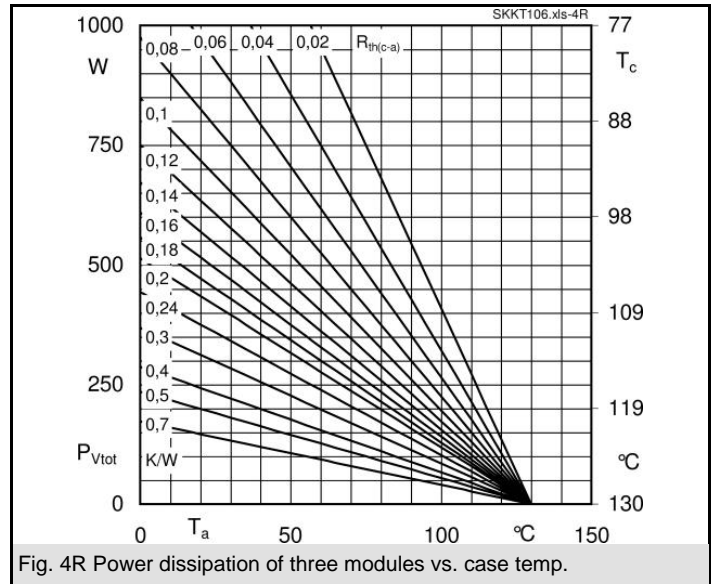
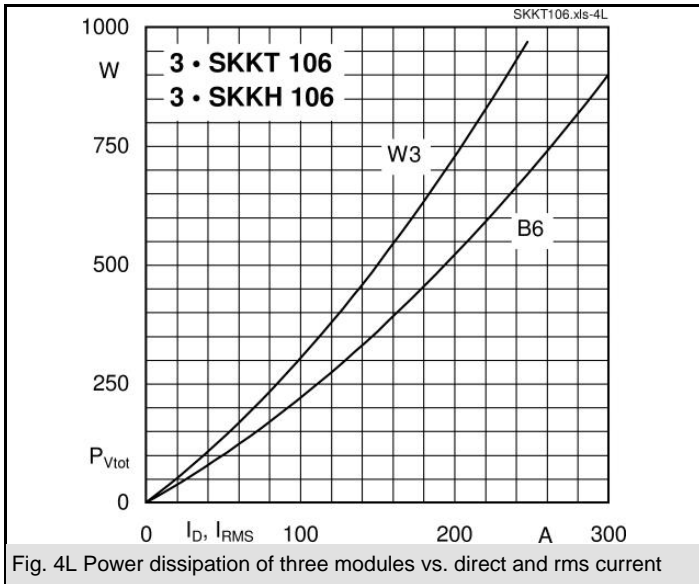
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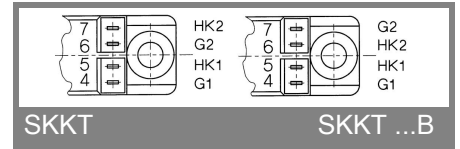
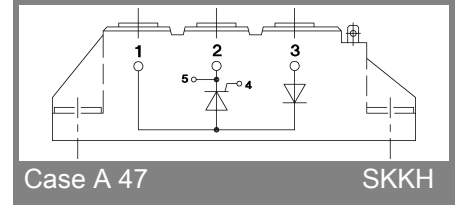
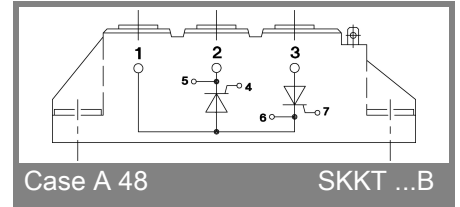
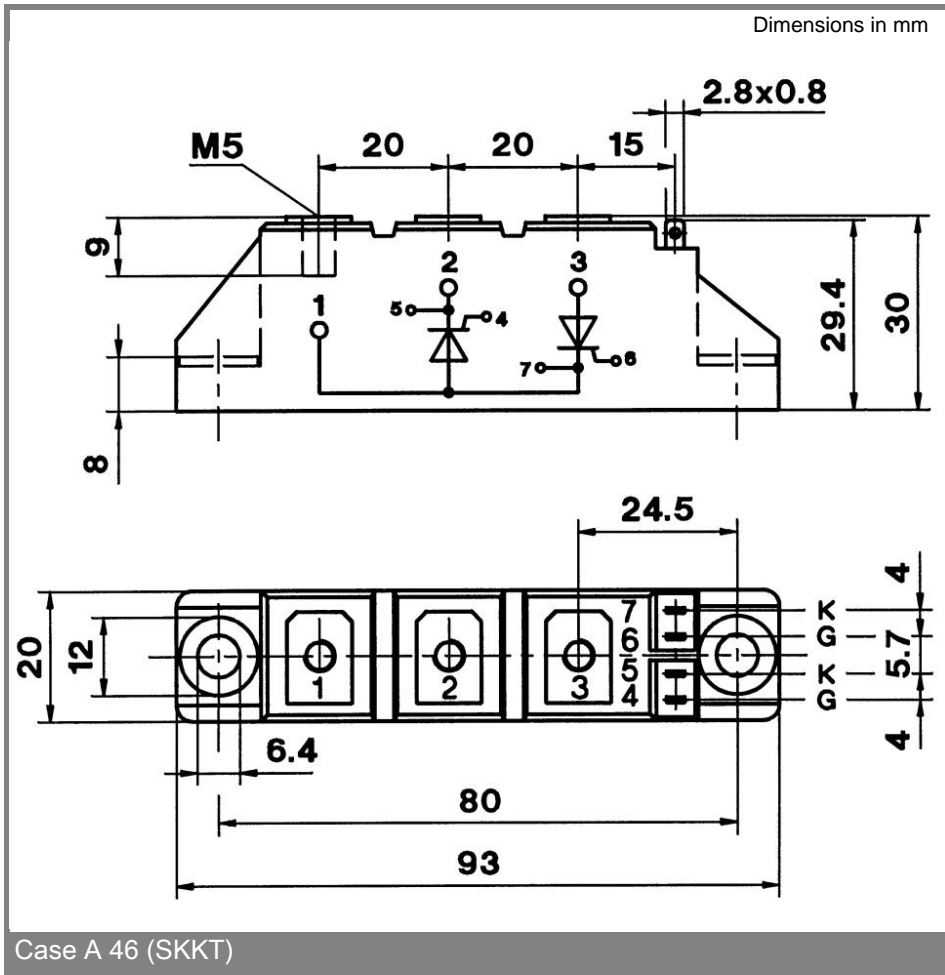
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